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We show that two capacitively-coupled Josephson junctions, in the quantum limit, form a simple coupled qubit system with e ective coupling controlled by the junction bias currents. We compute numerically the energy levels and wave functions for the system, and show how these may be tuned to make optimal qubits. The dependence of the energy levels on the parameters can be measured spectroscopically, providing an important experimental test for the presence of entangled multiqubit states in Josephson-junction based circuits.

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Ram os et al. have proposed that electrically wellisolated Josephson junctions can be used as qubits [1]. Two recent experim ents using di erent isolation schem es have reported Rabi oscillations in single junctions [2], dem onstrating the existence of macroscopic quantum coherence. W hile longer coherence times are desirable, these experim ents show that single Josephson junctions are strong candidates for solid-state qubits; several Josephson-based types have been proposed [3].

One of the next major steps towards building a Josephson-junction based quantum computer will be the observation of quantum properties of coupled macroscopic qubits. A simple scheme for making coupled qubits, junctions connected by capacitors, has recently been proposed by B lais et al. [4] and Ram os et al. [5]. This scheme is illustrated for the two-qubit case in Fig.1(a).

In this paper, we focus on the immediately accessible fundam ental experiments { spectroscopicm easurements of m acroscopically entangled quantum states { that are possible with this system . We calculate, using highly accurate numericalmethods, the energy levels and metastable wave functions for the circuit of Fig. 1 (a) in terms of the junction parameters, bias currents, and coupling capac-

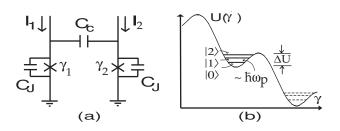


FIG.1: (a) (left) C incuit diagram for two idealized capacitively coupled Josephson junctions. (b) (right) The tilted washboard potential for a single current-biased Josephson junction with three metastable quantum states.

itance. Our num erical analysis dem onstrates that the system can be tuned to create appropriately spaced energy levels and coupled states. The features that we discuss can both guide the experim entale ort of observing multiqubit quantum states and provide help in optim izing the design of qubits and gates. But we emphatically stress that experim ental observation of these m acroscopic entangled quantum states will be an important achievem ent in its own right, and will provide strong support for the validity of m acroscopic quantum m echanics and the existence of m acroscopic entanglem ent [6]. Spectroscopic observation of these states should be possible by using standard single-junction experim ental techniques [5, 7].

The Ham iltonian for an ideal single current-biased Josephson junction, with critical current I_c and junction capacitance C_J ; is

H (;p) = $4E_{c} \sim {}^{2} p^{2} E_{J} (\cos + J);$ (1)

where is the gauge-invariant phase di erence across the junction, $J = I = I_c$; I is the (tunable) bias current, $E_J = (_0 I_c = 2)$ is the Josephson energy, $E_C = e^2 = 2C_J$ is the charging energy, and $_0 = h = 2e$ is the ux quantum. The canonicalm on entum is $p = (_0 = 2)^2 C_J = -Q = 2e$; where Q is the charge on the junction: The ratio $E_J = E_C$ determ ines whether the system is in a phase, charge, or interm ediate regime. The qubits explored in this paper have $E_J >> E_C$ and hence are in the phase regime.

The equations of motion for a single current-biased junction are equivalent to those for a particle in the tilted washboard potential shown in Fig. 1(b). Classically, for J < 1 there are stable minima about which the phase can oscillate with the characteristic plasma frequency $!_p(J) = \frac{P}{2} I_c = {}_0C_J 1 J^2 {}^{1=4}$ [8]. Quantum mechanically, the system exhibits localized metastable states in each well that can tunnel out into the running (nite-voltage) state. The elective barrier height U barrier [see Fig.1(b)] for a single junction in units of

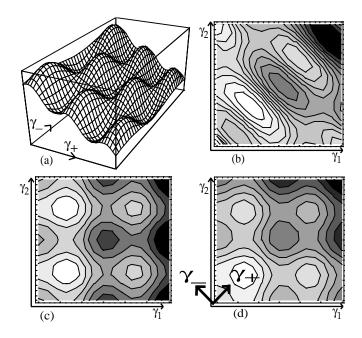


FIG.2: (a) Potential V⁰ with strong coupling (= 0.8) and $J_1 = J_2$. The coupling induces a squeezing in the + direction, relative to the direction. (b) V⁰ contours with = 0.8 and $J_1 \in J_2$, around the vicinity of one well. The symmetry of V⁰ shows that, despite detuned bias currents, + and are approximately the norm alm odes: (c) V⁰ with small coupling (= 0.01) and $J_1 \in J_2$ showing (by symmetry) that $_1$ and $_2$ are approximate norm alm odes. (d) V⁰ with = 0.01 and $J_1 = J_2$ showing that $_+$ and are norm alm odes.

 $\sim !_{p}$ (J); assuming J . 1; is related to N s by

$$N_{s}' \frac{U_{barrier}}{\sim !_{p} (J)} = \frac{2^{3=4}}{3} \frac{E_{J}}{E_{C}} (1 J)^{5=4} : (2)$$

Here, N_s is the approximate number of metastable bound states for a single isolated junction [8]. Our analysis explores the relevant regime for quantum computing where N_s is small and the nonlinearity of the Ham iltonian is important.

By adjusting the bias current it is possible to tune the barrier height to obtain, for example, three m etastable energy levels $E_0 < E_1 < E_2$ with the two lowest states forming the basis jDi; jLi of a qubit. State j2i has the highest escape rate due to tunneling and can therefore act as an auxiliary readout state, where readout is achieved by m icrow ave pumping at a frequency $!_{12} = (E_2 E_1) = : D$ etection of a voltage across the junction implies that the system was previously in the state jLi and has entered the running state.

The Ham iltonian for the coupled two-junction circuit shown in Fig.1(a) is

$$H = \frac{4E_{C}}{(1 + 1)^{2}} p_{1}^{2} + p_{2}^{2} + 2 p_{1}p_{2}$$
(3)

$$E_{L} (\cos_{1} + \cos_{2} + J_{1} + J_{2} + J_{2});$$

where = $C_c = (C_c + C_J)$ is the dimensionless coupling parameter, C_c is the coupling capacitance, and $J_{1,2}$ are the normalized bias currents of junctions 1 and 2, respectively. The canonical momenta, $p_{1,2} = (C_c + C_J) (_0=2)^2 (_{1,2} __{2,1})$; are proportional to the charges on each junction plus the charge on the coupling capacitor plate adjacent to it [4, 5].

By making a canonical change of variables, de ned by

$$p = 2(1)(p_1 p_2);$$
 (5)

we nd the transform ed H am iltonian

$$H^{0}(p_{+};p_{+};p_{+};p_{+}) = \frac{4E_{C}}{(1+)^{2}}p_{+}^{2} + p^{2} + V^{0}(+;p_{+};p_{+}):$$
(6)

Here, the momentum coupling term $2 p_1 p_2$ in the original H am iltonian is shifted to coupling in the new potential energy $V^0 = V^0(+;)$: Figures 2(a,b) illustrate how the coupling induces a squeezing of V^0 along the + direction; a strong coupling of = 0.8 has been chosen to accentuate this behavior.

W e gain further insight into the coupling of the junction states by looking at the norm alm odes for sm all oscillations. For sm all coupling and detuned bias currents $(J_1 \text{ far from } J_2)$ the norm alm odes are approxim ately $_1$ and $_2$; i.e., the junctions are electively decoupled. This elect is shown in Fig. 2 (c) by the approximate symmetry of V⁰ with respect to relations about the $_1$ and $_2$ axes. When $J_1 = J_2$ the norm alm odes become $_+$ and

; and we therefore expect the coupled junction states to be entangled sym metric and antisym metric combinations of the single junction states. This can be seen in Fig. 2 (d), where V⁰ is sym metric with respect to re ections about the $_{+}$ and axes. Figure 2 (b) shows V⁰ for = 0.8 and unequal bias currents; despite detuning the large prevents the junctions from decoupling and $_{+}$ and e ectively remain as norm alm odes.

The challenging dem ands of quantum computing require an accurate and precise quantitative description of the states going beyond simple perturbation theory. To achieve this, we have computed the states and energy levels num erically using a nonperturbative fast Fourier transform split-operator method [9] applied to the full nonlinear Hamiltonian in Eq. (3). Our implementation com putes the wave functions on a lattice using a fourthorder integration of the im aginary-tim e evolution operator exp (\hat{H}): W hile this method is relatively slow, its results for a subset of system parameters con m that the much faster complex scaling method [10] applied to the cubic approximation of the full potential [6] is accurate to at least 0.1%. The faster com plex scaling m ethod then allow sus to com pute energy levels for a wide range of system parameters. A further important property of both these num erical m ethods is that they are well suited to

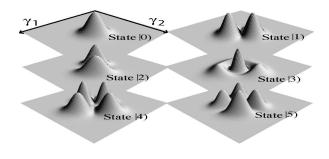


FIG. 3: The modulus squared of the probability amplitude of the rst six quasistationary wave functions for capacitively coupled current-biased Josephson junctions with coupling of = 0.01 and normalized bias currents of $J_1 = J_2 = 0.98693$:

nding m etastable states in potentials that allow tunneling, particularly in m one than one dim ension, where other m ethods fail. The computed quantum states have been further veri ed by time evolving them on a lattice using realtime split-operatorm ethods. This has con med dynam ically that these states are truly quasistationary and thus accurately determ ined; where applicable, agreem ent has also been found with higher-order W K B analysis.

In Fig. 3 we show, for example, the num erically com puted wave functions for identical junctions with capacitances $C_J = 43 \text{ pF}$ and critical currents $I_c = 133 \text{ A}$: Junctions with these physical characteristics are readily fabricated and of physical interest. Figure 3 shows the modulus squared of the wavefunctions of the rst six quasistationary states for the coupling strength = 0:01;and with bias currents $J_1 = J_2 = 0.98693$ such that isolated junctions would have approximately three quasistationary states (N $_{\rm s}$ $^\prime$ 3). These large bias currents m ake the nonlinearities of the potential pronounced, and the states deviate signi cantly from coupled harm onicoscillator states. The states jn) in Fig. 3 are ordered by energy E_n; a rounded bracket has been used to distinquish the coupled two-junction states in) from singlejunction states ini. The second and third states expressed in terms of single-junction direct product states are $jl) = (j01i \quad jl0i) = 2 \text{ and } j2) = (j01i + jl0i) = 2,$ whereas the higher-energy states are more complicated superpositions that depend upon the bias currents and coupling. The ordering of the states in Fig. 3 may be understood by looking at the potentials shown in Fig. 2 (a,b); wave functions extended in the + direction have higher energy because of the coupling induced effective squeezing in the + direction, relative to the direction. Observe that because the $(_1;_2)$ con guration space variables are the collective degrees of freedom of distinct junctions, the wave functions represent macroscopic nonlocally correlated (and hence entangled) states.

For designing qubits out of coupled junctions we need to know how the energy levels depend on coupling and bias current. Figure 4 shows the elects of varying the

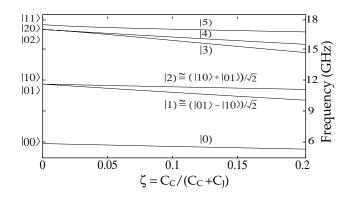


FIG . 4: Frequencies versus coupling strength for equal bias currents J_1 = J_2 = 0:98693, I_C = 13:3 A , and C_J = 4:3 pF .

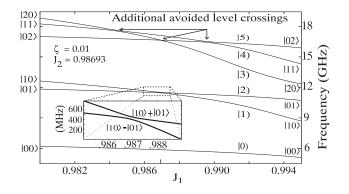


FIG.5: Frequencies of the rst six states versus bias current J_1 with J_2 = 0.98693 xed and a coupling strength of = 0.01, I_C = 13:3 A, and C_J = 4:3 pF.

coupling strength in the range 0 < 0.2 on the rst six energy levels with $J_1 = J_2 = 0.98693$: The plasm a frequency of each single junction when = 0 is $!_p (J_1 = J_2) = 2 = 6.2037$ GHz. The states are labeled at the left of Fig. 4 for zero coupling, where the product representation jm i = jni jm i is appropriate. For zero coupling the nonlinearity of the potential has broken the degeneracy between f_0 = jlli and the pair $(f_0) = j02i; f_4$ = j20i).

In real experiments, the coupling strength will typically be xed by the circuit design, and can only be varied by making a completely new sample. By contrast, the bias currents through each junction are easily varied, and allow manipulation of the entangled states shown in Fig. 3. Figure 5 shows how the energy levels change for = 0:01 and $J_2 = 0.98693$ xed, while J_1 is varied around J_2 . There are prominent avoided level crossings indicated in the gure for both on-tune ($J_1 = J_2$) and o -tune ($J_1 \in J_2$) bias currents. The predicted gap for the jl); j) on-tune splitting at $J_1 = 0.98693$ is 57 M H z for $I_C = 13:3$ A and C $_J = 4:3$ pF. The predicted gap for the rst o -tune splitting between states j4) and j5) at $J_1 = 0.98444$ is 80 M H z, and for the second o -tune

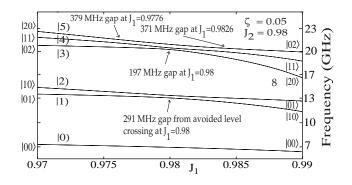


FIG. 6: Frequencies versus bias current J_1 with J_2 = 0.98 xed and a coupling strength of = 0.05; I_C = 13:3 A, and $C_{\rm J}$ = 4:3 pF.

splitting at $J_1 = 0.98962$ the gap is 72 MHz. The predicted gap for the on-tune β ; β splitting of 4 MHz is much smaller than the others because it is a second-order avoided crossing in perturbation theory. Figure 6 shows the energy levels for the same junction parameters but with = 0.05 and $J_2 = 0.98$ (N s ' 5).

W e have labeled the states in Figs. 5 and 6 at the far left and right{when the currents are detuned and hence the states are e ectively uncoupled{as product states. This labeling is only strictly correct when = 0. The mixing that occurs between states when the bias currents are brought into tune is indicated for the states jl) and j2) in Figs. 4 and 5. A swaplike gate operation can be constructed by exploiting this mixing [4].

Experimental data similar to Figs. 5 and 6 would be important rst evidence for the existence of macroscopic entangled states like those shown in Fig. 3. A typical experim ent to probe the energy levels in Figs. 4 {6 would proceed by preparing the system in the ground state \mathcal{D}) by cooling well below T ' $E_{\,01} {=} k$ ' 300 mK, where $E_{nm} = (E_n \quad E_m)$; and $E_n = E_n (J_i;)$ are the coupledjunction energies whose dependence on bias current and coupling we have shown in Figs. 4{6. Varying the bias current J1 (with J2 xed) while simultaneously injecting microwaves at a frequency ! should lead to an enhancem ent in the tunneling from the zero-voltage state to the nite-voltage running state of the system when $! = E_{nm}$ (J₁) =~: This enhancement produces a corresponding peak in escape rate measurements [5, 7]. By varying ! and J_1 for the coupled junctions, we may map out the energy levels for comparison with Figs. 5 and 6.

Experim entally, the expected energy gap between the avoided levels can be resolved if both the quality factor Q and coupling of the system are reasonably large. For example, with the typical junction parameters assumed here, and with = 0.01, the predicted gap for the jl), j2) splitting of 57 M H z can easily be resolved with a Q of 200 [5]. Furtherm ore, one can reasonably track the bending

of the resonant escape peaks near the avoided crossings within the span of a typical experim ental current window of about 30 nA [5]. These splittings can be made even easier to detect by increasing the coupling capacitance (see Fig. 6), though large coupling may inhibit e cient quantum gates.

In conclusion, we have presented predictions for fundam ental experim ents that probe m acroscopic entangled states by the relatively simple scheme of doing spectroscopy on coupled junctions while varying external bias currents. The energy levels of these entangled states should be readily observable using the same experim ental techniques that have allow ed spectroscopy of single junctions. The num erical methods we have used are powerful tools for mapping out the metastable states of nonlinear, many-level coupled systems, and allow us to explore a wide range of junction parameters and couplings. This kind of detailed study will be necessary for the design of realistic coupled qubits.

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